

SERIES UDN-3610M

DUAL 2-INPUT PERIPHERAL/POWER DRIVERS

FEATURES

- Four Logic Types
- DTL/TTL/PMOS/CMOS Compatible Inputs
- Low Input Current
- 300 mA Continuous Output Current
- Standoff Voltage of 80 V
- Pin-for-Pin Replacement for Series LM3600N
- Pin-for-Pin Replacement for SN75451BP through SN75454BP and 75461 through 75464

Description

THESE MINI-DIP dual 2-input peripheral power drivers are bipolar monolithic integrated circuits with AND, NAND, OR, or NOR logic gates and high-current switching transistors on the same chip. The two output transistors are capable of simultaneously sinking 300 mA continuously at ambient temperatures of up to +70°C. In the OFF state, these drivers will withstand at least 80 V.

Applications

Series UDN-3600M dual drivers are ideally suited for interface between low-level or high-level logic and high-current/high-voltage loads. Typical applications include driving peripheral loads such as incandescent lamps, light-emitting diodes, memories, heaters, and other non-inductive loads of up to 600 mA (both drivers in parallel).

With appropriate external-diode transient-suppression, Series UDN-3600M drivers can also be used with inductive loads such as relays, solenoids, and stepping motors.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{CC}	7.0 V
Input Voltage, V_{IN}	30 V
Output Off-State Voltage, V_{OFF}	80 V
Output On-State Sink Current, I_{ON}	600 mA
Power Dissipation, P_D	1.5 W
Each Driver	0.8 W
Derating Factor Above $T_A = 25^\circ\text{C}$	12.5 mW/°C or 80°C/W
Operating Free-Air Temperature Range, T_A	-20°C to +85°C
Storage Temperature Range, T_S	-55°C to +150°C

RECOMMENDED OPERATING CONDITIONS

	Min.	Nom.	Max.	Units
Supply Voltage (V_{CC})	4.75	5.0	5.25	V
Operating Temperature Range	0	+25	+85	°C
Current into any output (ON state)			300	mA

INPUT PULSE CHARACTERISTICS

$V_{in(OI)} = 0V$	$t_f = 7ns$	$t_p = 1\mu s$
$V_{in(I)} = 3.5V$	$t_r = 14ns$	PRR = 500kHz

ELECTRICAL CHARACTERISTICS over operating temperature range (unless otherwise noted)

Characteristic	Symbol	Test Conditions					Limits			Units	Notes
		Temp.	V_{CC}	Driven Input	Other Input	Output	Min.	Typ.	Max.		
"1" Input Voltage	$V_{in(I)}$		MIN				2.0			V	
"0" Input Voltage	$V_{in(O)}$		MIN						0.8	V	
"0" Input Current	$I_{in(O)}$		MAX	0.4 V	30 V		-50	-100		μA	2
"1" Input Current	$I_{in(I)}$		MAX	30 V	0 V				10	μA	2
Input Clamp Voltage	V_i		MIN	-12 mA					-1.5	V	

SWITCHING CHARACTERISTICS at $V_{CC} = 5.0V$, $T_A = 25^\circ C$

Characteristic	Symbol	Test Conditions	Limits			Units	Notes
			Min.	Typ.	Max.		
Turn-on Delay Time	t_{pDO}	$V_S = 70V$, $R_L = 465\Omega$ (10 Watts) $C_L = 15pF$		200	500	ns	3
Turn-off Delay Time	t_{pDI}	$V_S = 70V$, $R_L = 465\Omega$ (10 Watts) $C_L = 15pF$		300	750	ns	3

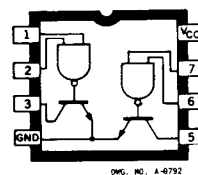
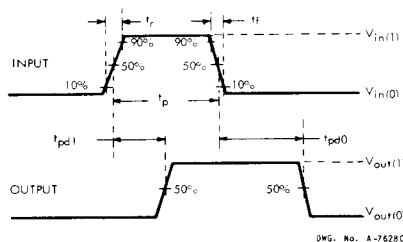
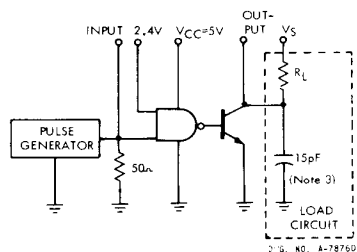
NOTES:

1. Typical values are at $V_{CC} = 5.0V$, $T_A = 25^\circ C$.
2. Each input tested separately.
3. Voltage values shown in the test circuit waveforms are with respect to network ground terminal.
4. Capacitance values specified include probe and test fixture capacitance.

Type UDN-3611M Dual AND Driver

ELECTRICAL CHARACTERISTICS over operating temperature range (unless otherwise noted)

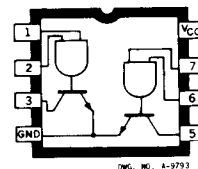
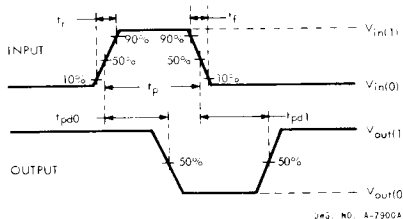
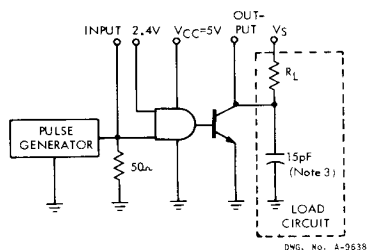
Characteristic	Symbol	Test Conditions					Limits				Notes
		Temp.	V _{CC}	Driven Input	Other Input	Output	Min.	Typ.	Max.	Units	
"1" Output Reverse Current	I _{off}		MIN	2.0 V	2.0 V	80 V			100	μA	
			OPEN	2.0 V	2.0 V	80 V			100	μA	
"0" Output Voltage	V _{on}		MIN	0.8 V	V _{CC}	100 mA		0.25	0.4	V	
			MIN	0.8 V	V _{CC}	300 mA		0.5	0.7	V	
"1" Level Supply Current	I _{CC(1)}	NOM	MAX	5.0 V	5.0 V			8.0	12	mA	1, 2
"0" Level Supply Current	I _{CC(0)}	NOM	MAX	0 V	0 V			35	49	mA	1, 2



Type UDN-3612M Dual NAND Driver

ELECTRICAL CHARACTERISTICS over operating temperature range (unless otherwise noted)

Characteristic	Symbol	Test Conditions					Limits				Notes
		Temp.	V _{CC}	Driven Input	Other Input	Output	Min.	Typ.	Max.	Units	
"1" Output Reverse Current	I _{off}		MIN	0.8 V	V _{CC}	80 V			100	μA	
			OPEN	0.8 V	V _{CC}	80 V			100	μA	
"0" Output Voltage	V _{on}		MIN	2.0 V	2.0 V	100 mA		0.25	0.4	V	
			MIN	2.0 V	2.0 V	300 mA		0.5	0.7	V	
"1" Level Supply Current	I _{CC(1)}	NOM	MAX	0 V	0 V			12	14	mA	1, 2
"0" Level Supply Current	I _{CC(0)}	NOM	MAX	5.0 V	5.0 V			40	53	mA	1, 2



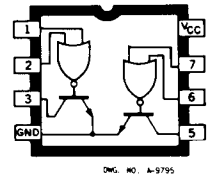
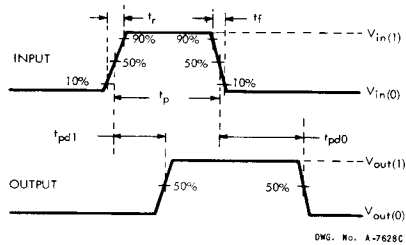
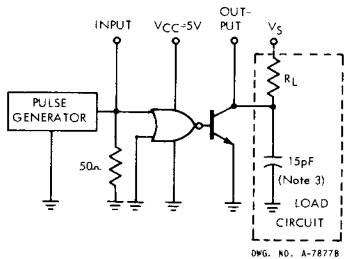
NOTES:

1. Typical values are at V_{CC} = 5.0 V, T_A = 25°C.
2. Per package.
3. Capacitance values specified include probe and test fixture capacitance.

Type UDN-3613M Dual OR Driver

ELECTRICAL CHARACTERISTICS over operating temperature range (unless otherwise noted)

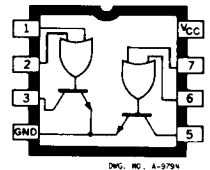
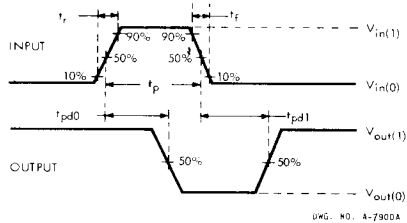
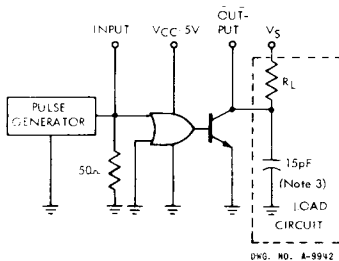
Characteristic	Symbol	Test Conditions				Limits				Notes
		Temp.	V _{CC}	Driven Input	Other Input	Output	Min.	Typ.	Max.	
"1" Output Reverse Current	I _{off}		MIN	2.0 V	0 V	80 V			100	μA
			OPEN	2.0 V	0 V	80 V			100	μA
"0" Output Voltage	V _{on}		MIN	0.8 V	0.8 V	100 mA	0.25	0.4		V
			MIN	0.8 V	0.8 V	300 mA	0.5	0.7		V
"1" Level Supply Current	I _{CC(1)}	NOM	MAX	5.0 V	5.0 V		8.0	13		mA
"0" Level Supply Current	I _{CC(0)}	NOM	MAX	0 V	0 V		36	50		mA



Type UDN-3614M Dual NOR Driver

ELECTRICAL CHARACTERISTICS over operating temperature range (unless otherwise noted)

Characteristic	Symbol	Test Conditions				Limits				Notes
		Temp.	V _{CC}	Driven Input	Other Input	Output	Min.	Typ.	Max.	
"1" Output Reverse Current	I _{off}		MIN	0.8 V	0.8 V	80 V			100	μA
			OPEN	0.8 V	0.8 V	80 V			100	μA
"0" Output Voltage	V _{on}		MIN	2.0 V	0 V	100 mA	0.25	0.4		V
			MIN	2.0 V	0 V	300 mA	0.5	0.7		V
"1" Level Supply Current	I _{CC(1)}	NOM	MAX	0 V	0 V		12	15		mA
"0" Level Supply Current	I _{CC(0)}	NOM	MAX	5.0 V	5.0 V		40	50		mA



NOTES:

1. Typical values are at V_{CC} = 5.0 V, T_A = 25°C.
2. Per package.
3. Capacitance values specified include probe and test fixture capacitance.